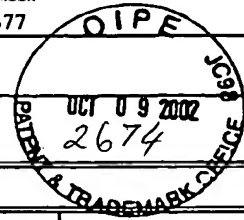


Form PTO 1449 U.S. Department of Commerce Patent and Trademark Office Information Disclosure Statement by Applicant	ATTY. DOCKET NUMBER NITT.0057	SERIAL NUMBER 10/031,377
	APPLICANT SUZUKI et al.	
	FILING DATE April 12, 2002	GROUP



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EXAMINER: Initial if citation is considered, whether or not citation is in conformance with MPEP 609; draw a line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant		

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JC13 Rec'd PCT/PTO 18 JAN 2002

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